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I. BAND STRUCTURE: INSIGHT FROM DFT COMPUTATIONS

A. Computational details

First principles calculations are used for the investigation of the electronic properties of TlEr_2Se_2 and TlTm_2Se_2 . Ab initio calculations were performed using the pseudopotential projector-augmented wave method [1] implemented in the Vienna ab initio simulation package (VASP) [2, 3] with an energy cutoff of 700 eV for the plane wave basis set. A Γ -centred $28 \times 28 \times 28$ k-point mesh was used to sample the Brillouin zone. Spin-orbit coupling effects were included self-consistently. We used the experimental low-temperature crystal structure to initialize our computations from Materials project database [5]. The f -electrons of Er and Tm were treated as core electrons. Nonmagnetic configuration were chosen. Post-processing produced with pymatgen python library [4].

II. RESULTS

Fig. 1 shows the band structure and the density of states (DOS) in TlEr_2Se_2 . The top of the valence band is set at zero energy and the scale is in electron volt. As the valence band maxima and the conduction band minima lies on the T and the point between the F and Γ points [ARTEM, pls look at the correspondence band and dos. Minima in band is lower than in DOS *fixed]. Hence, this shows the indirect band gap nature in TlEr_2Se_2 . The value of the gap is 1eV [ARTEM in band - 0.9 pls check. *fixed] When Er is replaced by Tm, the band gap is similar to the previous case, as shown in Fig. 2. The top of the valence bands in both materials consists predominantly from p -states of Se. The conduction band electrons originated both from the orbitals of d electrons of Er(Tm) and p electrons of Tl.

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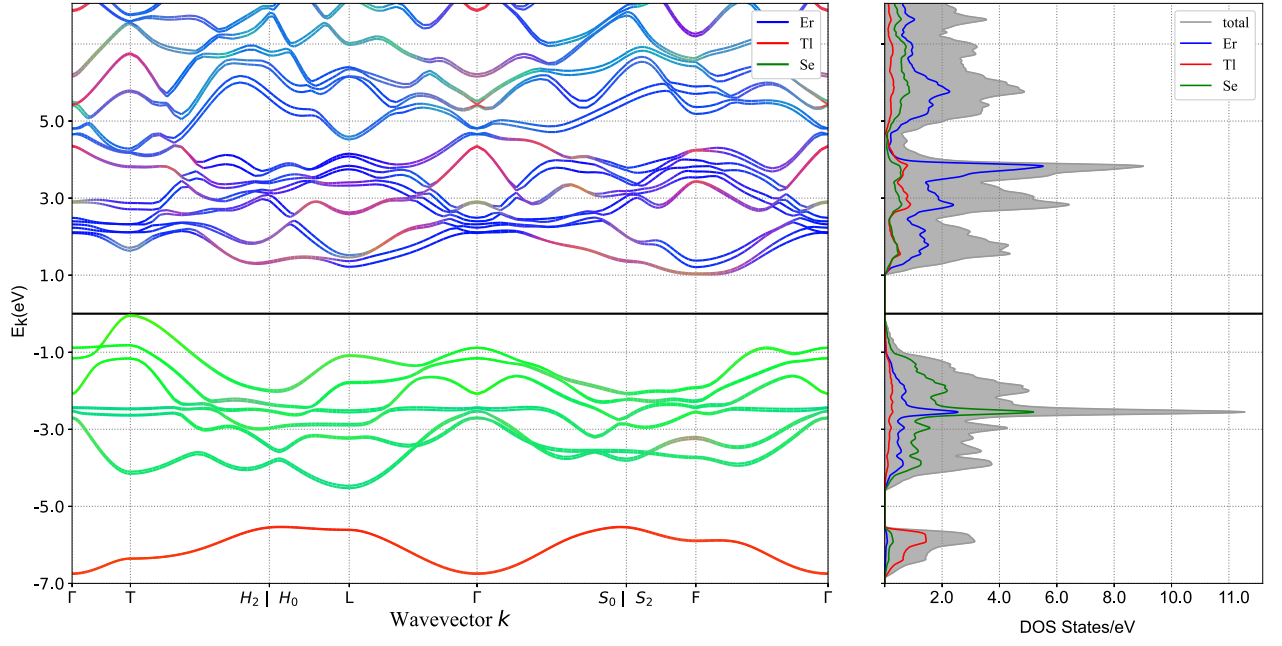


Figure 1: Band structure and density of states of TlEr_2Se_2 .

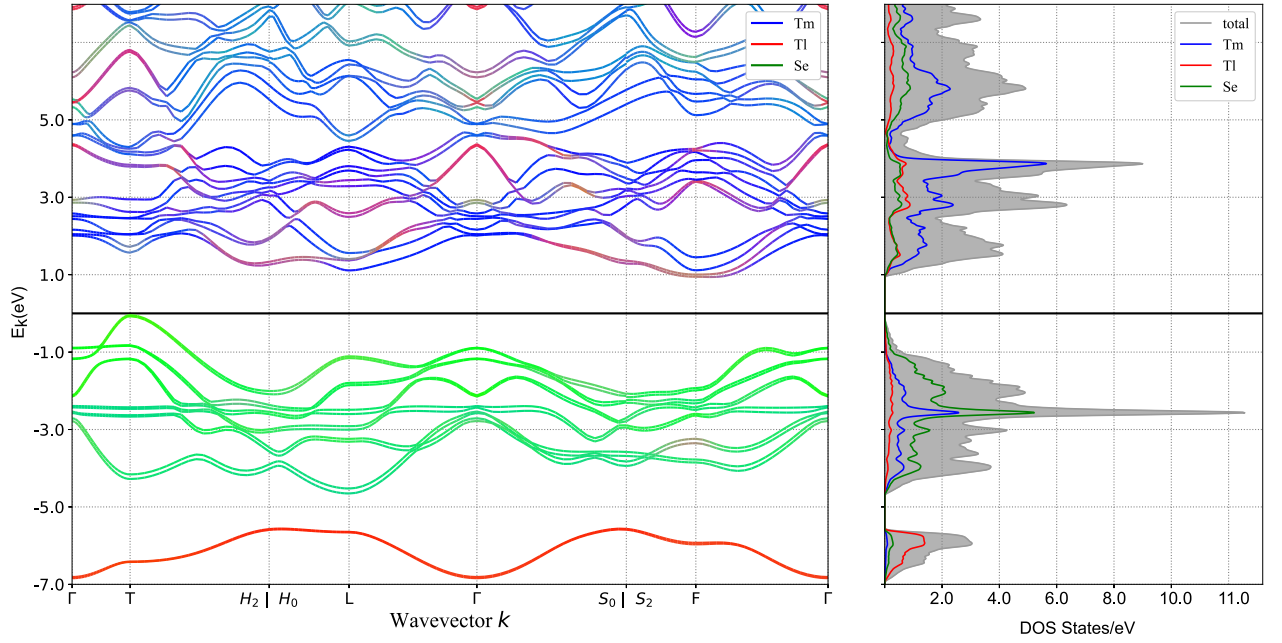


Figure 2: Band structure and density of states of TlTm_2Se_2 .